

NPN SILICON RF TRANSISTOR 2SC5012

NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW-NOISE AMPLIFICATION 4-PIN SUPER MINIMOLD

FEATURES

- High Gain Bandwidth Product (fr = 9 GHz TYP.)
- · Low Noise, High Gain
- · Low Voltage Operation
- · 4-pin super minimold Package

★ ORDERING INFORMATION

Part Number	Quantity	Supplying Form
2SC5012	50 pcs (Non reel)	• 8 mm wide embossed taping
2SC5012-T1	3 kpcs/reel	Pin 3 (Base), Pin 4 (Emitter) face to perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office.

The unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS ($T_A = +25$ °C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	20	V
Collector to Emitter Voltage	VCEO	10	V
Emitter to Base Voltage	V _{EBO}	1.5	V
Collector Current	lc	65	mA
Total Power Dissipation	Ptot Note	150	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T _{stg}	-65 to +150	°C

Note Free air

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.



ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit	
DC Characteristics							
Collector Cut-off Current	Ісво	VcB = 10 V, IE = 0 mA	-	-	1.0	μΑ	
Emitter Cut-off Current	ІЕВО	V _{EB} = 1 V, I _C = 0 mA	-	-	1.0	μΑ	
DC Current Gain	hfe Note 1	VcE = 8 V, Ic = 20 mA	50	100	250	-	
RF Characteristics							
Gain Bandwidth Product	f⊤	VcE = 8 V, Ic = 20 mA	-	9.0	-	GHz	
Insertion Power Gain	S _{21e} ²	VcE = 8 V, Ic = 20 mA, f = 1.0 GHz	13	15	-	dB	
Noise Figure	NF	VcE = 8 V, Ic = 7 mA, f = 1.0 GHz	-	1.2	2.5	dB	
Reverse Transfer Capacitance	Cre Note 2	VcB = 10 V, IE = 0 mA, f = 1.0 MHz	-	0.25	0.8	pF	

Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded

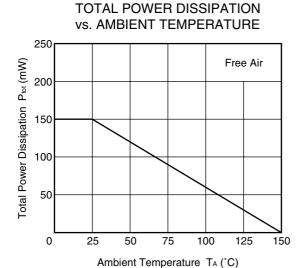
hfe CLASSIFICATION

Rank	EB	FB	GB
Marking	R36	R37	R38
h _{FE} Value	50 to 100	80 to 160	125 to 250

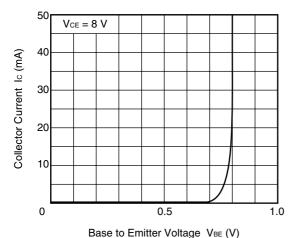
2



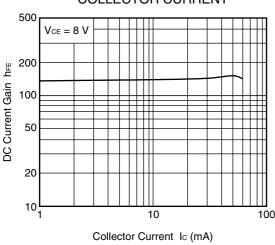
TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)



COLLECTOR CURRENT vs. **BASE TO EMITTER VOLTAGE**

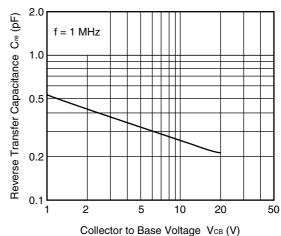


DC CURRENT GAIN vs. **COLLECTOR CURRENT**

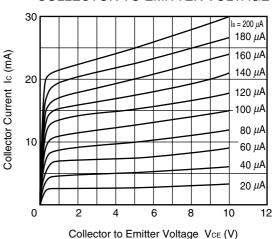


Remark The graphs indicate nominal characteristics.

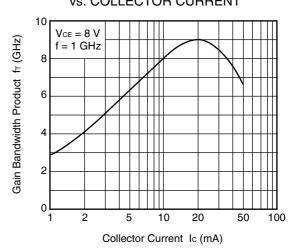
REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

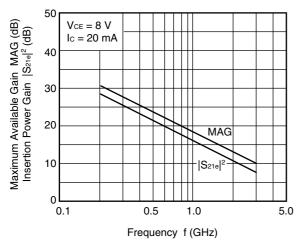


GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

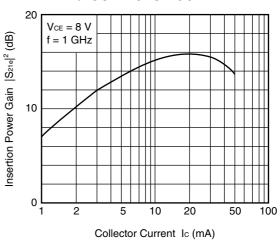




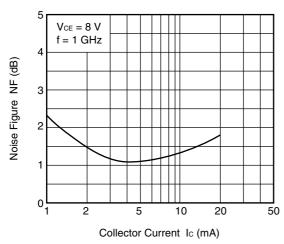
MAXIMUM AVAILABLE GAIN/INSERTION POWER GAIN vs. FREQUENCY



INSERTION POWER GAIN vs. COLLECTOR CURRENT



NOISE FIGURE vs. COLLECTOR CURRENT



Remark The graphs indicate nominal characteristics.

★ S-PARAMETERS

S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

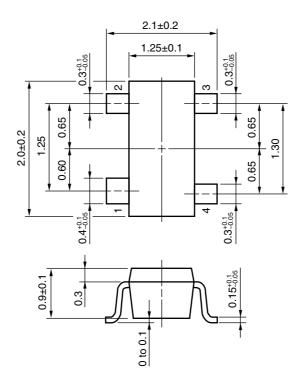
Click here to download S-parameters.

[RF and Microwave] \rightarrow [Device Parameters]

URL http://www.ncsd.necel.com/

★ PACKAGE DIMENSIONS

4-PIN SUPER MINIMOLD (UNIT: mm)



PIN CONNECTIONS

- 1. Collector
- 2. Emitter
- 3. Base
- 4. Emitter

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- The information in this document is current as of July, 2004. The information is subject to change
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▶ For further information, please contact

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